

Rated to +175°C – Ideal for High Ambient Temperature

Lead-Free Finish; RoHS Compliant (Notes 1 & 2) Halogen and Antimony Free. "Green" Device (Note 3) The DMTH10H015SK3Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in

https://www.diodes.com/quality/product-definitions/

Case Material: Molded Plastic, "Green" Molding Compound.

Terminals: Finish - Matte Tin Annealed over Copper Leadframe.

UL Flammability Classification Rating 94V-0 Moisture Sensitivity: Level 1 per J-STD-020 Terminal Connections: See Diagram

Solderable per MIL-STD-202, Method 208 @3

Weight: 0.33 grams (Approximate)

100% Unclamped Inductive Switching - Ensures More Reliable

Features

Environments

Mechanical Data

Case: TO252

and Robust End Application

IATF 16949 certified facilities.

Low R_{DS(ON)} – Minimizes Power Losses Low Q_g –Minimizes Switching Losses

Product Summary

BV _{DSS}	Rds(on) Max	Ι _D Tc = +25°C
100V	14mΩ @ V _{GS} = 10V	59A
	20mΩ @ V _{GS} = 6V	50A

Description

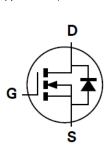
This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Power Management Functions
- DC-DC Converters
- Backlighting

Top View

TO252 (DPAK)

Pin Out Top View



Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMTH10H015SK3Q-13	TO252 (DPAK)	2500/Tape & Reel

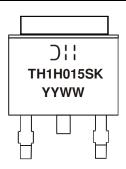
EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:



) | | = Manufacturer's Marking TH1H015SK = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 21 = 2021) WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit		
Drain-Source Voltage		VDSS	100	V		
Gate-Source Voltage		Vgss	±20	V		
Continuous Drain Current, V _{GS} = 10V	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	ID	59 42	А		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		Ідм	235	А		
Maximum Continuous Body Diode Forward Current (Note 6)		ls	2.7	А		
Pulsed Body Diode Forward Current (10µs Pulse, T _C = +25°C, Pack	age Limited)	I _{SM}	235	А		
Avalanche Current, L = 0.1mH		I _{AS}	15.8	А		
Avalanche Energy, L = 0.1mH		valanche Energy, L = 0.1mH		Eas	12.5	mJ
Avalanche Current, L = 3mH (Note 8)		las	7.5	А		
Avalanche Energy, L = 3mH (Note 8)		E _{AS}	85	mJ		

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Total Power Dissipation (Note 5)		PD	2	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	RθJA	75	°C/W	
Total Power Dissipation (Note 6)		PD	3.7	W	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{θJA}	40	°C/W	
Thermal Resistance, Junction to Case		R _{0JC}	2	C/VV	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C	

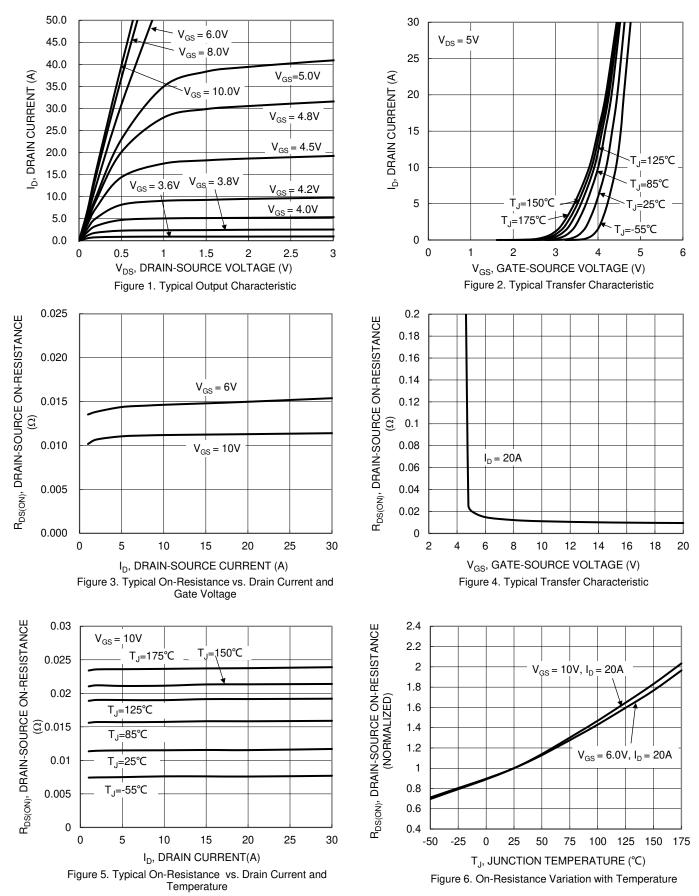
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)			•		1		
Drain-Source Breakdown Voltage	BVDSS	100	—	_	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS	_	—	1	μΑ	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	_	—	±100	nA	$V_{GS}=\pm 20V, \ V_{DS}=0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	2	-	4	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance			11.1	14	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance	RDS(ON)		14.7	20	11152	$V_{GS} = 6V, I_D = 20A$	
Diode Forward Voltage	V _{SD}		0.86	1.3	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	—	2343	_		$V_{DS} = 50V, V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss	_	487	_	pF		
Reverse Transfer Capacitance	Crss	_	26	_			
Gate Resistance	Rg	_	0.69	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	30.1	_			
Gate-Source Charge	Q _{gs}		7.5	-	nC	$V_{DD} = 50V, I_D = 10A, V_{GS} = 10V$	
Gate-Drain Charge	Q _{gd}		6.5			VGS = 10V	
Turn-On Delay Time	td(ON)		9.8	_			
Turn-On Rise Time	tR		7.8	-		$\label{eq:VDD} \begin{split} V_{DD} &= 50V, \ V_{GS} = 10V, \\ I_D &= 10A, \ R_g = 6\Omega \end{split}$	
Turn-Off Delay Time	td(OFF)		22.5	_	ns		
Turn-Off Fall Time	tF	—	9.6	_			
Reverse Recovery Time	trr	_	43	_	ns		
Reverse Recovery Charge	Q _{RR}	_	65.1	_	nC	I _F = 10A, di/dt = 100A/μs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:

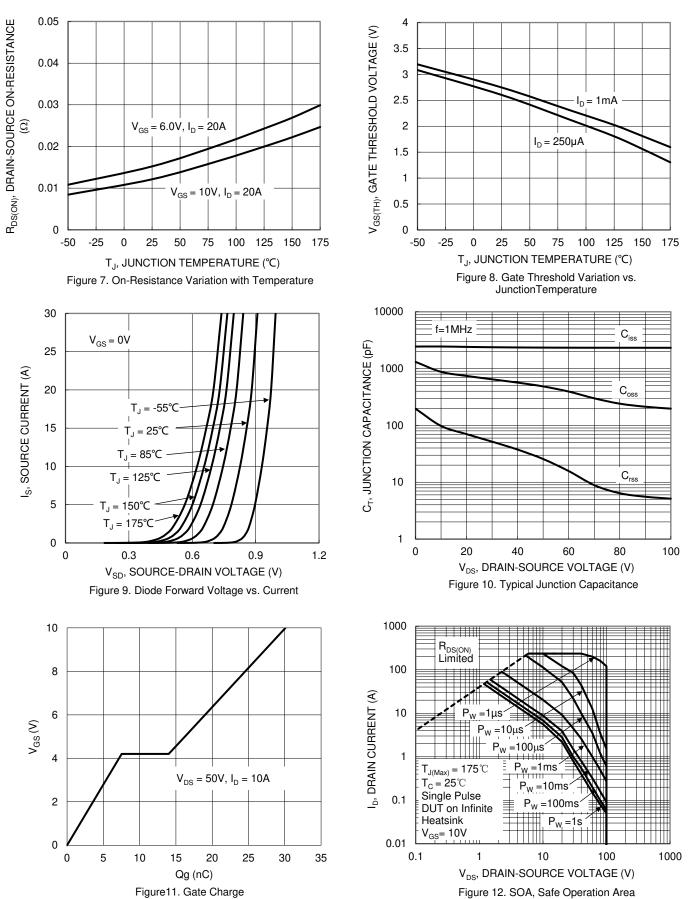


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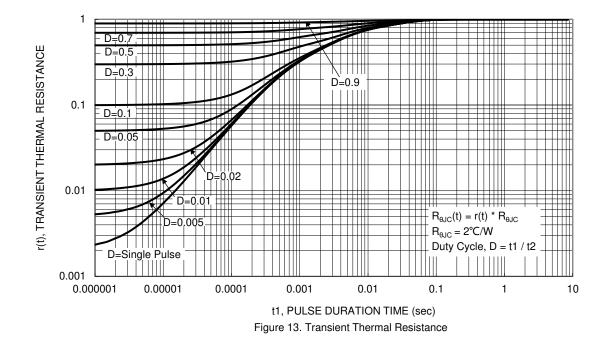


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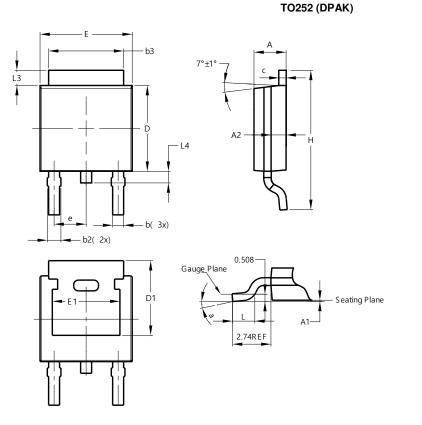






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

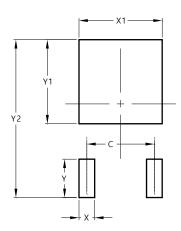


TO252 (DPAK)						
Dim	Min	Max	Тур			
Α	2.19	2.39	2.29			
A1	0.00	0.13	0.08			
A2	0.97	1.17	1.07			
q	0.64	0.88	0.783			
b2	0.76	1.14	0.95			
b3	5.21	5.46	5.33			
С	0.45	0.58	0.531			
D	6.00	6.20	6.10			
D1	5.21	-	-			
е	-	-	2.286			
Е	6.45	6.70	6.58			
E1	4.32	-	-			
Η	9.40	10.41	9.91			
L	1.40	1.78	1.59			
L3	0.88	1.27	1.08			
L4	0.64	1.02	0.83			
а	0°	10°	-			
All	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK)



Dimensions	Value (in mm)			
С	4.572			
Х	1.060			
X1	5.632			
Y	2.600			
Y1	5.700			
Y2	10.700			



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